

**In the Claims:**

**Please rewrite claims 1, 3-5, 8 and 9 as follows:**

1. (Currently Amended) A semiconductor light-emitting element comprising:  
a substrate,  
a first epitaxial layer group to emit a yellow color light ~~which is provided on the~~  
substrate and made of II-VI semiconductor compounds, and  
a second epitaxial layer group to emit a blue color light ~~which is provided on the~~  
substrate and made of II-VI semiconductor compounds.
- B' 2. (Original) A semiconductor light-emitting element as defined in claim 1, wherein  
the first epitaxial layer group includes a light-emitting active layer made of a II-VI  
semiconductor compound containing Zn, Se, Te and Cd.
3. (Currently Amended) A semiconductor light-emitting element as defined in claim 2,  
wherein the light-emitting active layer is made of a II-VI semiconductor compound having a  
composition of  $\text{Zn}_{1-X}\text{Cd}_X\text{Se}_{1-Y}\text{Te}_Y$  ( $0.1 < X \leq 0.4$ ,  $0.1 < Y < 0.4$ ).
4. (Currently Amended) A semiconductor light-emitting element as defined in claim 2;  
wherein the first epitaxial layer group includes a first optical waveguide layer and a second  
optical waveguide layer which ~~are provided so as to sandwich the light-emitting active layer~~  
and are made of II-VI semiconductor compounds containing Be and Mg, respectively.
5. (Currently Amended) A semiconductor light-emitting element as defined in claim 4;  
wherein the first epitaxial layer group includes a first cladding layer and a second cladding

| layer which ~~are provided so as to~~ sandwich the first optical waveguide layer and the second  
| optical waveguide layer mon the outside of the first and the second optical waveguide layers,  
| and are made of II-VI semiconductor compounds containing Be and Mg, respectively.

6. (Original) A semiconductor light-emitting element as defined in claim 1, wherein  
the second epitaxial layer group includes a light-emitting active layer made of a II-VI  
semiconductor compound containing Zn, Se, Te and Cd.

7. (Original) A semiconductor light-emitting element as defined in claim 6, wherein  
the light-emitting active layer is made of a II-VI semiconductor compound having a  
composition of  $\text{Zn}_{1-z}\text{Cd}_z\text{Se}_{1-v}\text{Te}_v$  ( $0 < z < 0.1$ ,  $0 < v < 0.1$ ).

8. (Currently Amended) A semiconductor light-emitting element as defined in claim 6,  
wherein the second epitaxial layer group includes a first optical waveguide layer and a second  
| optical waveguide layer which ~~are provided so as to~~ sandwich the light-emitting active layer  
| and are made of II-VI semiconductor compounds containing Be and Mg, respectively.

9. (Currently Amended) A semiconductor light-emitting element as defined in claim 8,  
wherein the second epitaxial layer group includes a first cladding layer and a second cladding  
| layer which ~~are provided so as to~~ sandwich the first optical waveguide layer and the second  
| optical waveguide layer mon the outside of the first and the second optical waveguide layers,  
| and are made of II-VI semiconductor compounds containing Be and Mg, respectively.

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